LSIC2SD120E15CC



Circuit Diagram TO247-3L



Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability

Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Solar inverters

Pò

diodes

• Extremely fast,

temperature-independent

switching behavior

• Dramatically reduced

compared to Si bipolar

switching losses

Industrial motor drives

H F RoHS 🕅

- EV charging stations
- Uninterruptible power supplies

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "PB-free" logo
- = Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	1200	V	
DC Blocking Voltage	V _R	T _j = 25 °C	1200	V	
Continuous Forward Current (Per Leg/Device)	I _F	T _c = 25 °C	24.5/49	A	
		T _c = 135 °C	12/24		
		T _c = 154 °C	8/16		
Non-Repetitive Forward Surge Current (Per Leg)	I	$T_c = 25 \text{ °C}, T_p = 10 \text{ ms}, \text{ Half sine pulse}$	65	А	
Power Dissipation	P _{Tot}	$T_c = 25 \text{ °C}$	125/250	- W	
(Per Leg/Device)		T _c = 110 °C	54/108		
Operating Junction Temperature	Tj	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature	T _{sold}	-	260	°C	

Electrical Characteristics (Per Leg)

Ohanna stanistica	Cumhal	Oralitions		Value		
Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit
Forward Valtage	V	I _F = 8 A, T _J = 25 °C	-	1.5	1.8	V
Forward Voltage	V _F	I _F = 8 A, T _J = 175 °C	-	2.2	-	V
		V _R = 1200 V , T _J = 25 °C	-	<1	100	μA
Reverse Current	I _R	V _R = 1200 V , T _J = 175 °C	-	10		
		V _R = 1 V, f =1 MHz	-	454	-	
Total Capacitance	С	V _R = 400 V, f = 1 MHz	-	45	-	pF
		V _R = 800 V, f = 1 MHz	-	33 -		
otal Capacitive Charge	Q _c	$V_{R} = 800 \text{ V}, $	-	47	-	nC

Footnote: T_J = +25 °C unless otherwise specified

Thermal Characteristics						
Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ. Ma	Max.	
Thermal Resistance (Per Device/Leg)	R _{ejc}	-	-	1.2/0.6	-	°C/W

Figure 1: Typical Foward Characteristics (Per Leg)



Figure 2: Typical Reverse Characteristics (Per Leg)







Figure 4: Current Derating (Per Leg)



Figure 5: Capacitance vs. Reverse Voltage (Per Leg)



Figure 6: Capacitive Charge vs. Reverse Voltage (Per Leg)







Figure 8: Transient Thermal Impedance (Per Device)

Package Dimensions TO-247-3L



Recommended Hole Pattern Layout



Notes:

1. Dimensions are in millimeters 2. Dimension D, E do not include mold flash. Mold flash shall not exceed 0.127 mm per side measured at outer most extreme of plastic body. **3**,gP to have a maximum draft angle of 38.1 mm to the top of the part with a maximum hole diameter of 3.912 mm.

O mark at	Millimeters			
Symbol	Min	Nom	Мах	
Α	4.80	5.03	5.20	
A1	2.25	2.38	2.54	
A2	1.85	1.98	2.11	
b	0.99	-	1.40	
b2	1.65	-	2.39	
b4	2.59	-	3.43	
С	0.38	0.64	0.89	
D	20.80	20.96	21.34	
D1	13.50	-	-	
D2	0.51	1.19	1.35	
е		5.44 B	SC	
Е	15.75	15.90	16.13	
E1	13.06	14.02	14.15	
E2	4.19	4.32	4.83	
L	19.81	20.19	20.57	
L1	3.81	4.19	4.45	
øP	3.55	3.61	3.66	
øP1	7.06	7.19	7.32	
Q	5.49	5.61	6.20	
S	6.05	6.17	6.30	

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GEN2 SiC Schottky Diode LSIC2SD120E15CC, 1200 V, 15 A, TO-247-3L

Part Numbering and Marking System SIC = SiC = Gen2 2 SD = Schottky Diode SIC2SD120E15CC 120 = Voltage Rating (1200 V) LF YYWWE Е = T0-247-3L ZZZZZZ-ZZ 15 = Current Rating (15 A) CC = Common Cathode YΥ = Year WW = Week = Special Code Е ZZZZZZ-ZZ = Lot Number

Packing Options					
Part Number	Marking	Packing Mode	М.О.Q		
LSIC2SD120E15CC	SIC2SD120E15CC	Tube (30pcs)	450		

Packing Specification TO-247-3L



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0.846±0.02 (21.488±0.508)

- 0.063±0.008 (1.600±0.203)

0.030±0.004 (0.762±0.102)